

400 V, 0.5 A PNP high-voltage low VCEsat (BISS) transistor28 September 2017Product data sheet

# 1. General description

 $\label{eq:PNP-high-voltage-low-V} PNP \ high-voltage \ low-V_{CEsat} \ Breakthrough \ In \ Small \ Signal \ (BISS) \ transistor \ in \ a \ SOT89 \ (SC-62) \ medium \ power \ and \ flat \ lead \ Surface-Mounted \ Device \ (SMD) \ plastic \ package.$ 

NPN complement: PBHV8540X

# 2. Features and benefits

- High voltage
- Low collector-emitter saturation voltage V<sub>CEsat</sub>
- High collector current capability  $I_C$  and  $I_{CM}$
- High collector current gain (h<sub>FE</sub>) at high I<sub>C</sub>
- AEC-Q101 qualified

## 3. Applications

- Electronic ballast for fluorescent lighting
- LED driver for LED chain module
- LCD backlighting
- High Intensity Discharge (HID) front lighting
- Automotive motor management
- Hook switch for wired telecom
- Switch mode power supply

## 4. Quick reference data

Table 1. Quick reference data							
Symbol	Parameter	Conditions		Min	Тур	Max	Unit
V <sub>CEO</sub>	collector-emitter voltage	open base		-	-	-400	V
I <sub>C</sub>	collector current			-	-	-0.5	А
I <sub>CM</sub>	peak collector current	single pulse; $t_p \le 1 \text{ ms}$		-	-	-1	А
h <sub>FE</sub>	DC current gain	$V_{CE}$ = -5 V; I <sub>C</sub> = -20 mA; T <sub>amb</sub> = 25 °C		140	-	450	
R <sub>CEsat</sub>	collector-emitter saturation resistance	$I_{C}$ = -200 mA; $I_{B}$ = -40 mA; $T_{amb}$ = 25 °C	[1]	-	-	2000	mΩ

[1] Pulse test:  $t_p \le 300 \ \mu s$ ;  $\delta \le 0.02$ 



# 5. Pinning information

Table 2. I	Pinning inf	formation		
Pin	Symbol	Description	Simplified outline	Graphic symbol
1	E	emitter		C
2	С	collector		вщ
3	В	base	3 2 1 SOT89	E sym132

# 6. Ordering information

Table 3. Ordering information						
Type number	Package	'ackage				
	Name	Description	Version			
PBHV9540X	SOT89	plastic surface-mounted package; die pad for good heat transfer; 3 leads	SOT89			

## 7. Marking

Table 4. Marking codes	
Type number	Marking code[1]
PBHV9540X	%4H

[1] % = placeholder for manufacturing site code

# 8. Limiting values

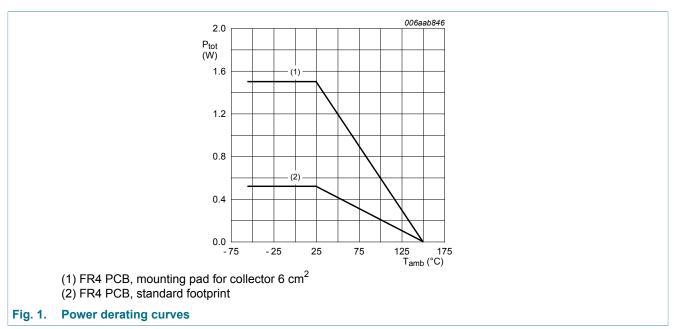
#### Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions		Min	Мах	Unit
V <sub>CBO</sub>	collector-base voltage	open emitter		-	-400	V
V <sub>CEO</sub>	collector-emitter voltage	open base		-	-400	V
V <sub>CESM</sub>	collector-emitter peak voltage	V <sub>BE</sub> = 0 V		-	-400	V
V <sub>EBO</sub>	emitter-base voltage	open collector		-	-7	V
I <sub>C</sub>	collector current			-	-0.5	А
I <sub>CM</sub>	peak collector current	single pulse; $t_p \le 1 \text{ ms}$		-	-1	А
I <sub>B</sub>	base current			-	-250	mA
P <sub>tot</sub>	total power dissipation	T <sub>amb</sub> ≤ 25 °C	[1]	-	0.52	W
			[2]	-	1.5	W
Tj	junction temperature			-	150	°C
T <sub>amb</sub>	ambient temperature			-55	150	°C
T <sub>stg</sub>	storage temperature			-65	150	°C

[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

[2] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for collector 6 cm<sup>2</sup>.

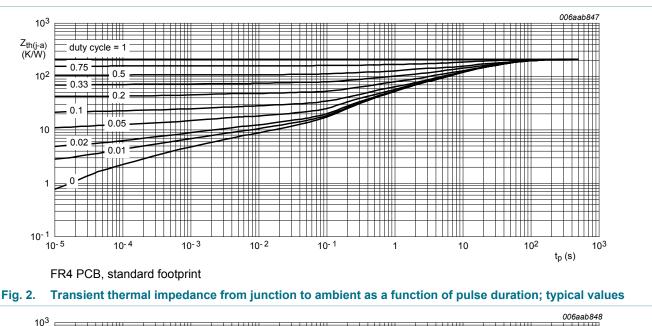


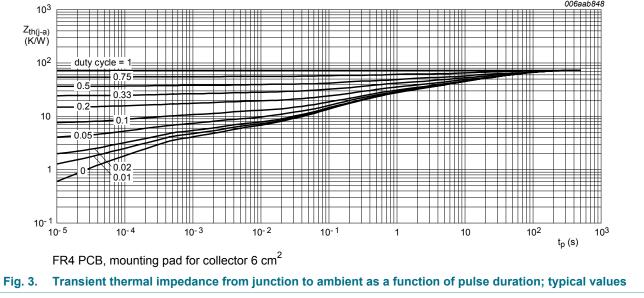
## 9. Thermal characteristics

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
R <sub>th(j-a)</sub> thermal resis from junction ambient	thermal resistance		[1]	-	-	240	K/W
	-		[2]	-	-	83	K/W
R <sub>th(j-sp)</sub>	thermal resistance from junction to solder point			-	20	-	K/W

[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

[2] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for collector 6 cm<sup>2</sup>.





# **10. Characteristics**

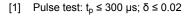
Symbol	Parameter	Conditions		Min	Тур	Max	Unit
V <sub>(BR)CBO</sub>	collector-base breakdown voltage	$I_{C}$ = -100 µA; $I_{E}$ = 0 A; $T_{amb}$ = 25 °C		-400	-	-	V
V <sub>(BR)CEO</sub>	collector-emitter breakdown voltage	$I_{C}$ = -2.5 mA; $I_{B}$ = 0 A; $T_{amb}$ = 25 °C		-400	-	-	V
V <sub>(BR)CES</sub>	collector-emitter breakdown voltage (base shorted)	$I_{C}$ = -2.5 mA; $V_{BE}$ = 0 V; $T_{amb}$ = 25 °C		-400	-	-	V
V <sub>(BR)EBO</sub>	emitter-base breakdown voltage (collector open)	$I_E$ = -100 µA; $I_C$ = 0 A; $T_{amb}$ = 25 °C		-7	-	-	V
I <sub>CBO</sub>	collector-base cut-off	V <sub>CB</sub> = -320 V; I <sub>E</sub> = 0 A; T <sub>amb</sub> = 25 °C		-	-	-100	nA
	current	V <sub>CB</sub> = -320 V; I <sub>E</sub> = 0 A; T <sub>j</sub> = 150 °C		-	-	-10	μA
I <sub>CES</sub>	collector-emitter cut-off current	$V_{CE}$ = -320 V; $V_{BE}$ = 0 V; $T_{amb}$ = 25 °C		-	-	-100	nA
I <sub>EBO</sub>	emitter-base cut-off current	$V_{EB}$ = -7 V; I <sub>C</sub> = 0 A; T <sub>amb</sub> = 25 °C		-	-	-100	nA
h <sub>FE</sub>	DC current gain	$V_{CE}$ = -5 V; I <sub>C</sub> = -20 mA; T <sub>amb</sub> = 25 °C		140	-	450	
		$V_{CE}$ = -5 V; I <sub>C</sub> = -100 mA; T <sub>amb</sub> = 25 °C	[1]	140	-	400	
V <sub>CEsat</sub>	collector-emitter saturation voltage	$I_{C}$ = -100 mA; $I_{B}$ = -20 mA; $T_{amb}$ = 25 °C	[1]	-	-	-250	mV
		I <sub>C</sub> = -200 mA; I <sub>B</sub> = -40 mA;	[1]	-	-	-400	mV
R <sub>CEsat</sub>	collector-emitter saturation resistance	T <sub>amb</sub> = 25 °C	[1]	-	-	2000	mΩ
V <sub>BEsat</sub>	base-emitter saturation voltage	$I_{C}$ = -100 mA; $I_{B}$ = -10 mA; $T_{amb}$ = 25 °C	[1]	-	-	-0.9	V
		$I_{C}$ = -200 mA; $I_{B}$ = -40 mA; $T_{amb}$ = 25 °C	[1]	-	-	-1	V
V <sub>BE</sub>	base-emitter voltage	$V_{CE}$ = -10 V; I <sub>C</sub> = -200 mA; T <sub>amb</sub> = 25 °C	[1]	-	-	-0.9	V
t <sub>d</sub>	delay time	V <sub>CC</sub> = -6.2 V; I <sub>C</sub> = -100 mA;		-	60	-	ns
t <sub>r</sub>	rise time	I <sub>Bon</sub> = -10 mA; I <sub>Boff</sub> = 20 mA; T <sub>amb</sub> = 25 °C		-	3650	-	ns
t <sub>on</sub>	turn-on time			-	3710	-	ns
t <sub>s</sub>	storage time	_		-	810	-	ns
t <sub>f</sub>	fall time			-	900	-	ns
t <sub>off</sub>	turn-off time			-	1710	-	ns
f <sub>T</sub>	transition frequency	$V_{CE}$ = -5 V; I <sub>C</sub> = -50 mA; f = 100 MHz; T <sub>amb</sub> = 25 °C		-	65	-	MHz
C <sub>c</sub>	collector capacitance	V <sub>CB</sub> = -10 V; I <sub>E</sub> = 0 A; i <sub>e</sub> = 0 A; f = 1 MHz; T <sub>amb</sub> = 25 °C		-	14	-	pF

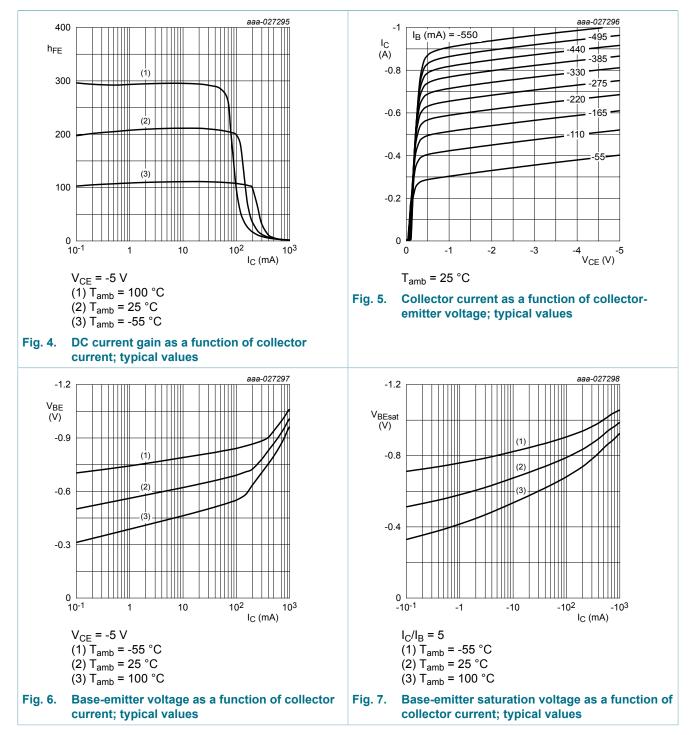
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# **PBHV9540X**

### 400 V, 0.5 A PNP high-voltage low VCEsat (BISS) transistor

Symbol	Parameter	Conditions	Min	Тур	Мах	Unit
C <sub>e</sub>	emitter capacitance	$V_{EB}$ = -0.5 V; I <sub>C</sub> = 0 A; i <sub>c</sub> = 0 A; f = 1 MHz; T <sub>amb</sub> = 25 °C	-	235	-	pF

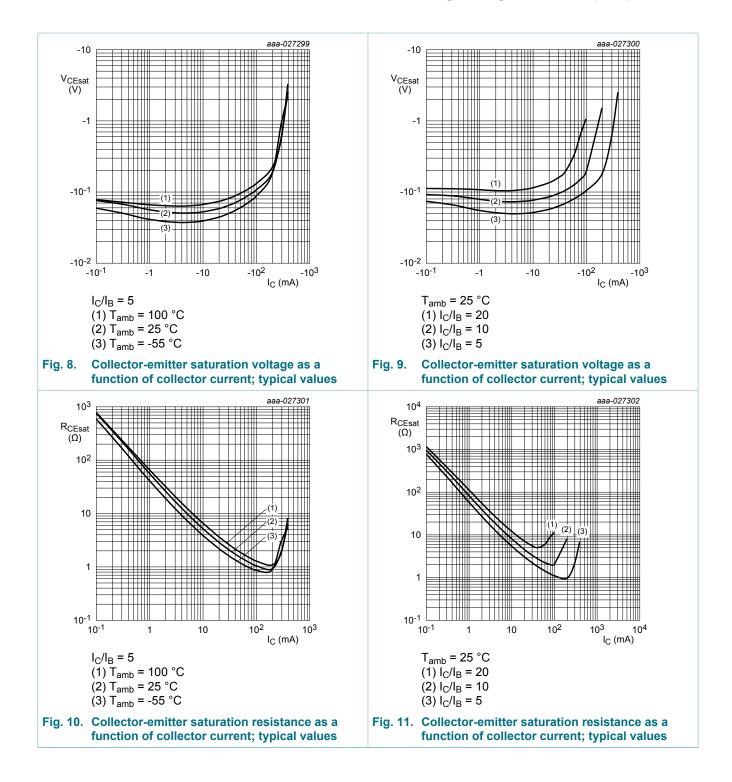




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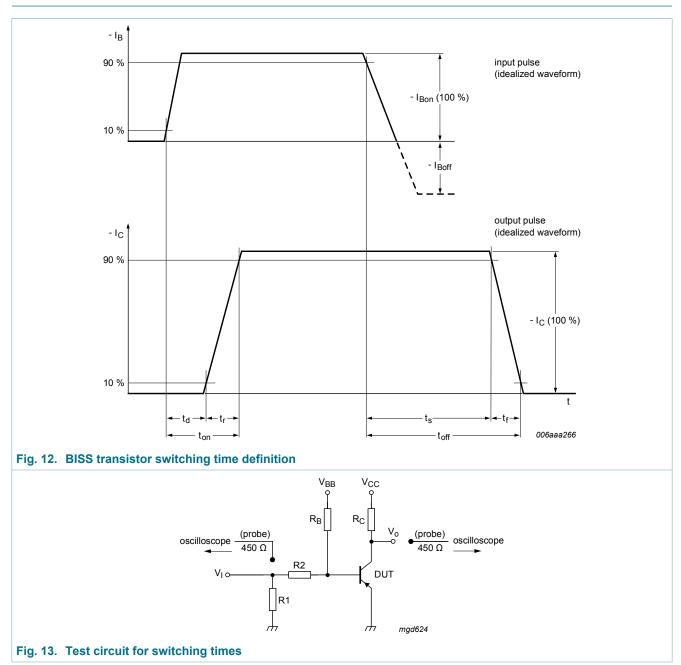
# **PBHV9540X**

#### 400 V, 0.5 A PNP high-voltage low VCEsat (BISS) transistor



**Product data sheet** 

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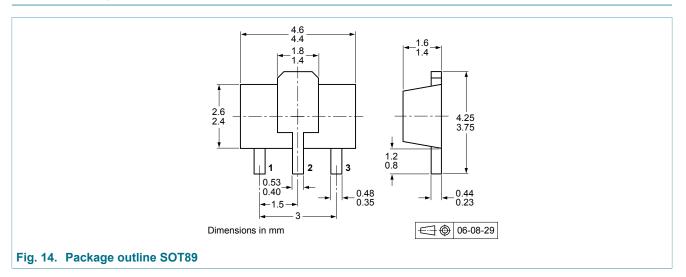


## 11. Test information

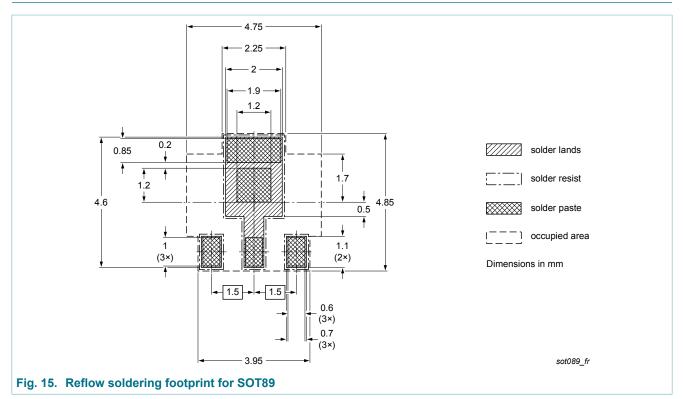
#### **Quality information**

This product has been qualified in accordance with the Automotive Electronics Council (AEC) standard *Q101* - *Stress test qualification for discrete semiconductors*, and is suitable for use in automotive applications.

## 12. Package outline

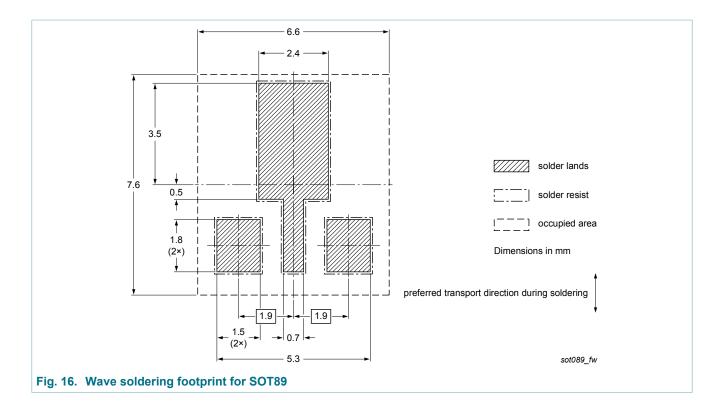


# 13. Soldering



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# 14. Revision history

Table 8. Revision history					
Data sheet ID	Release date	Data sheet status	Change notice	Supersedes	
PBHV9540X v.1	20170928	Product data sheet	-	-	

#### 400 V, 0.5 A PNP high-voltage low VCEsat (BISS) transistor

# 15. Legal information

#### **Data sheet status**

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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